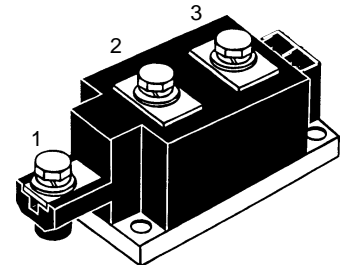


High Power Diode Modules

$I_{FRMS} = 2 \times 450 \text{ A}$
 $I_{FAVM} = 2 \times 270 \text{ A}$
 $V_{RRM} = 1200\text{-}2200 \text{ V}$

V_{RSM} V_{DSM} V	V_{RRM} V_{DRM} V	Type
1300	1200	MDD 255-12N1
1500	1400	MDD 255-14N1
1700	1600	MDD 255-16N1
1900	1800	MDD 255-18N1
2100	2000	MDD 255-20N1
2300	2200	MDD 255-22N1



Symbol	Test Conditions	Maximum Ratings	
I_{FRMS}	$T_{VJ} = T_{VJM}$	450 A	
I_{FAVM}	$T_C = 100^\circ\text{C}; 180^\circ \text{ sine}$	270 A	
I_{FSM}	$T_{VJ} = 45^\circ\text{C}; V_R = 0$	t = 10 ms (50 Hz) 9500 A t = 8.3 ms (60 Hz) 10200 A	
	$T_{VJ} = T_{VJM}; V_R = 0$	t = 10 ms (50 Hz) 8400 A t = 8.3 ms (60 Hz) 9000 A	
$\int i^2 dt$	$T_{VJ} = 45^\circ\text{C}; V_R = 0$	t = 10 ms (50 Hz) 451 000 A ² s t = 8.3 ms (60 Hz) 437 000 A ² s	
	$T_{VJ} = T_{VJM}; V_R = 0$	t = 10 ms (50 Hz) 353 000 A ² s t = 8.3 ms (60 Hz) 340 000 A ² s	
T_{VJ}		-40...+150 °C	
T_{VJM}		150 °C	
T_{stg}		-40...+125 °C	
V_{ISOL}	50/60 Hz, RMS	t = 1 min 3000 V~	
	$I_{ISOL} \leq 1 \text{ mA}$	t = 1 s 3600 V~	
M_d	Mounting torque (M6)	4.5-7/40-62 Nm/lb.in.	
	Terminal connection torque (M8)	11-13/97-115 Nm/lb.in.	
Weight	Typical including screws	750 g	
Symbol	Test Conditions	Characteristic Values	
I_{RRM}	$T_{VJ} = T_{VJM}; V_R = V_{RRM}$	30 mA	
V_F	$I_F = 600 \text{ A}; T_{VJ} = 25^\circ\text{C}$	1.4 V	
V_{T0}	For power-loss calculations only	0.8 V	
r_T	$T_{VJ} = T_{VJM}$	0.6 mΩ	
R_{thJC}	per diode; DC current per module	} other values see MCC 255	0.140 K/W
			0.07 K/W
R_{thJK}	per diode; DC current per module	}	0.18 K/W
			0.09 K/W
Q_s	$T_{VJ} = 125^\circ\text{C}; I_F = 400 \text{ A}; -di/dt = 50 \text{ A}/\mu\text{s}$	700 μC	
I_{RM}		260 A	
d_s	Creeping distance on surface	12.7 mm	
d_A	Creepage distance in air	9.6 mm	
a	Maximum allowable acceleration	50 m/s ²	

Features

- International standard package
- Direct copper bonded Al₂O₃-ceramic with copper base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered E 72873

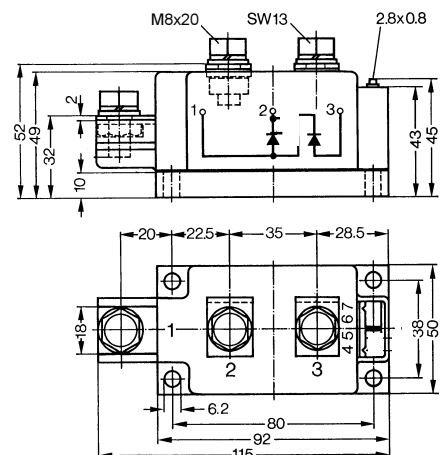
Applications

- Supplies for DC power equipment
- DC supply for PWM inverter
- Field supply for DC motors
- Battery DC power supplies

Advantages

- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

Dimensions in mm (1 mm = 0.0394")



Data according to IEC 60747 and refer to a single diode unless otherwise stated. IXYS reserves the right to change limits, test conditions and dimensions

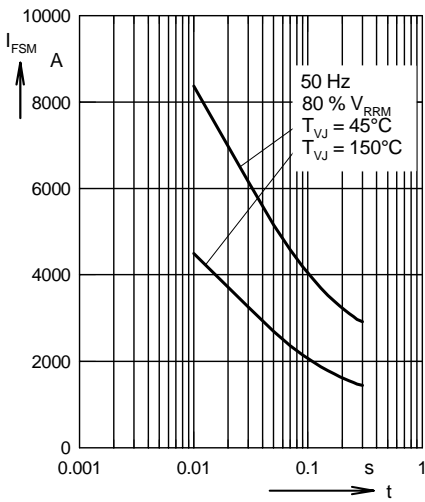


Fig. 1 Surge overload current
 I_{FSM} : Crest value, t : duration

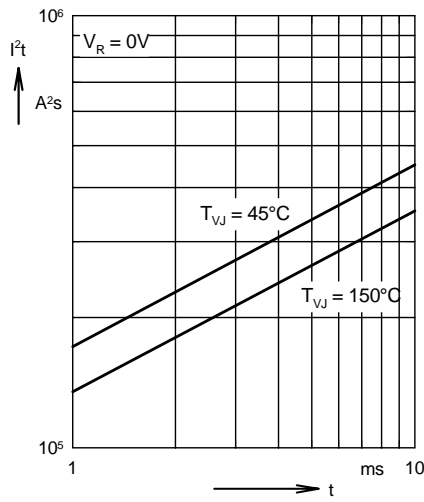


Fig. 2 I^2t versus time (1-10 ms)

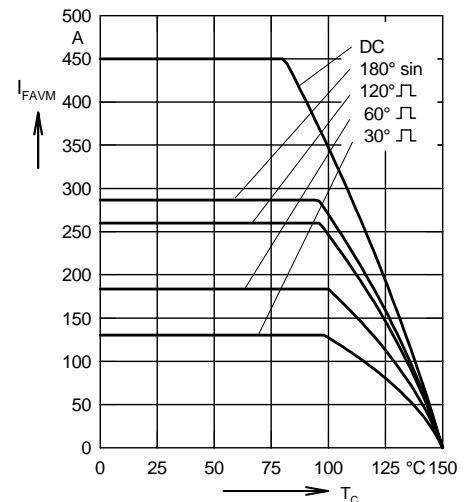


Fig. 3 Maximum forward current at case temperature

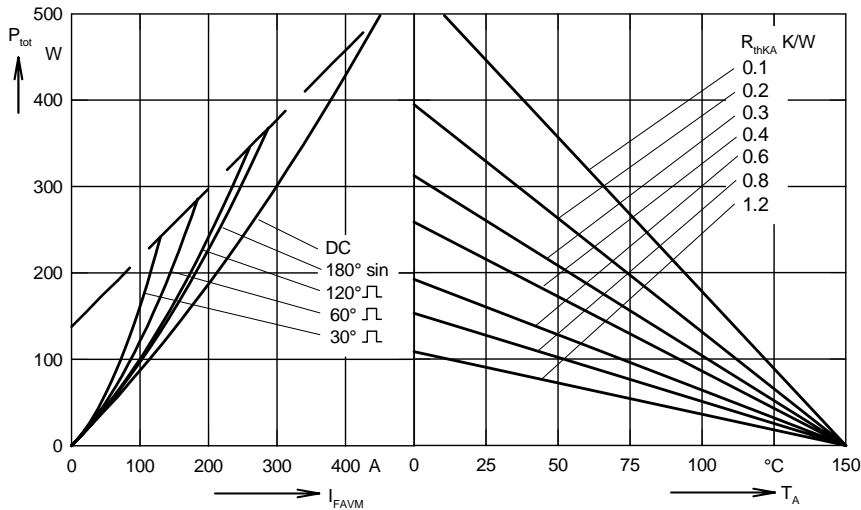


Fig. 4 Power dissipation versus forward current and ambient temperature (per diode)

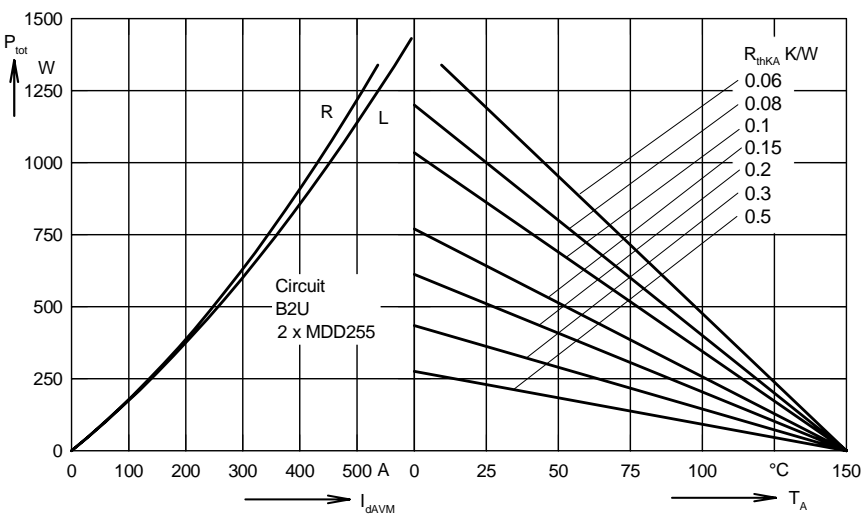


Fig. 5 Single phase rectifier bridge:
 Power dissipation versus direct output current and ambient temperature
 R = resistive load
 L = inductive load

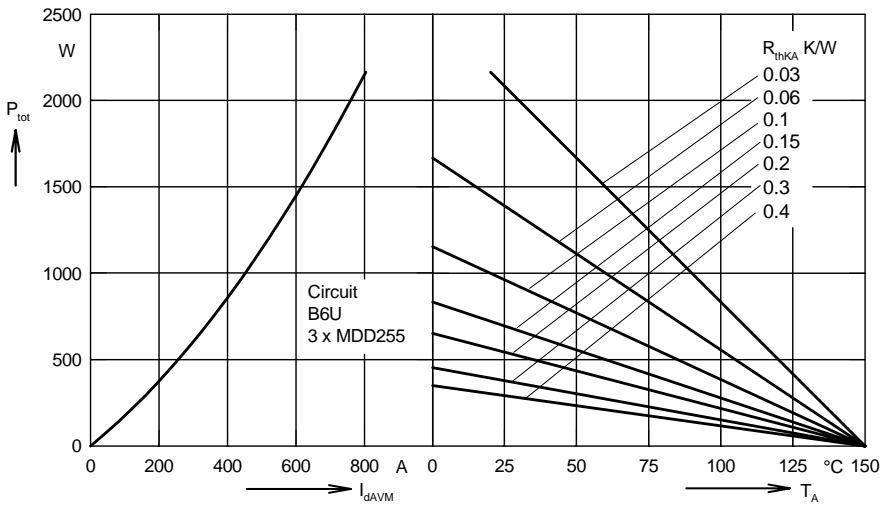


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

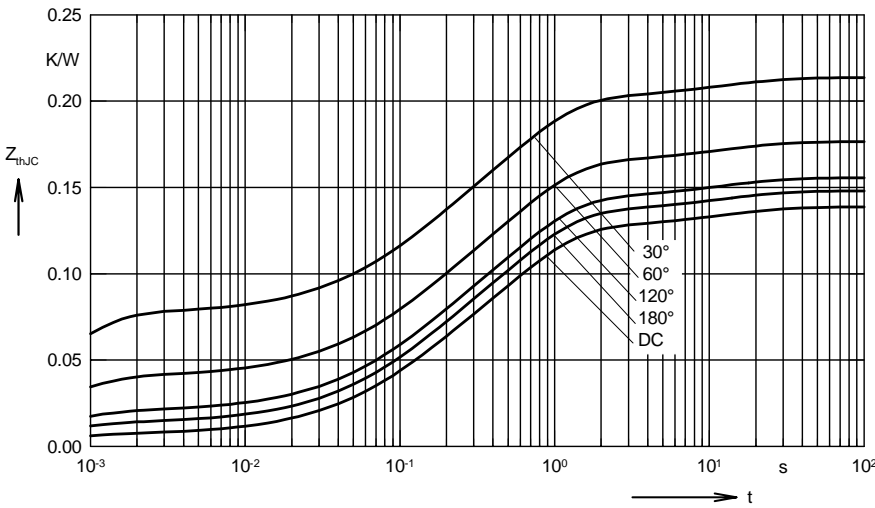


Fig. 7 Transient thermal impedance junction to case (per diode)

R_{thJC} for various conduction angles d:

d	R_{thJC} (K/W)
DC	0.139
180°	0.148
120°	0.156
60°	0.176
30°	0.214

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.0066	0.00054
2	0.0358	0.098
3	0.0831	0.54
4	0.0129	12

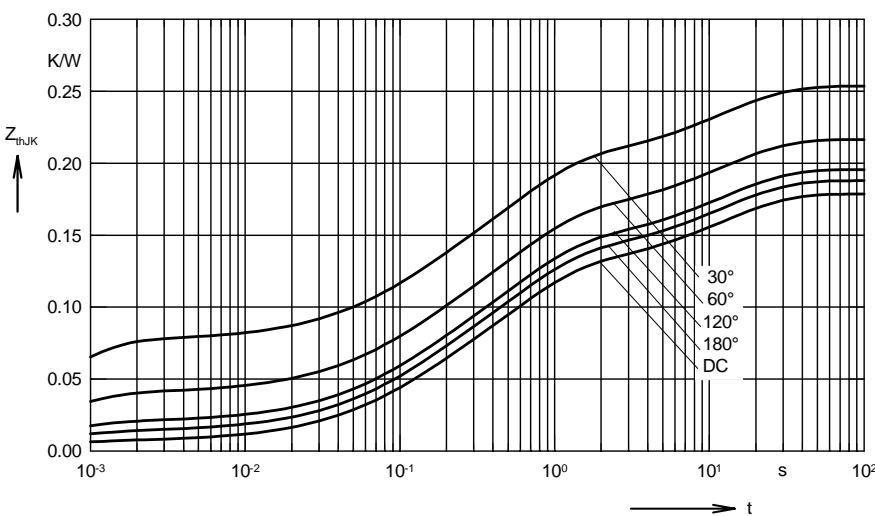


Fig. 8 Transient thermal impedance junction to heatsink (per diode)

R_{thJK} for various conduction angles d:

d	R_{thJK} (K/W)
DC	0.179
180°	0.188
120°	0.196
60°	0.216
30°	0.254

Constants for Z_{thJK} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.0066	0.00054
2	0.0358	0.098
3	0.0831	0.54
4	0.0129	12
5	0.04	12